

Tandem solar cells activities at CSEM and EPFL in Neuchâtel

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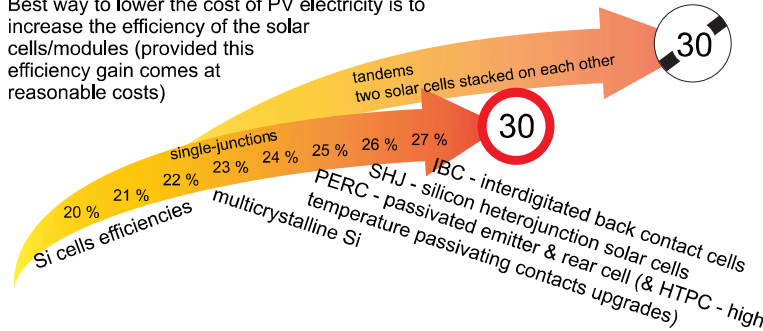
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Silicon solar cell technologies approach their efficiency limit

Solar cells using a single light absorber are limited in efficiency to about 30% or less
 With a record at 26.7%, best-in-class silicon solar cells are close to their practical efficiency limit (about 27%)

Problematic on the longer term due to the cost distribution of a PV system dominated by balance of system components

Best way to lower the cost of PV electricity is to increase the efficiency of the solar cells/modules (provided this efficiency gain comes at reasonable costs)



Objectives of the research on tandems at CSEM & EPFL PVLAB

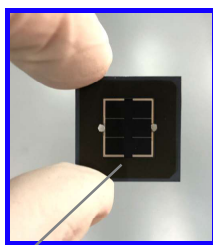
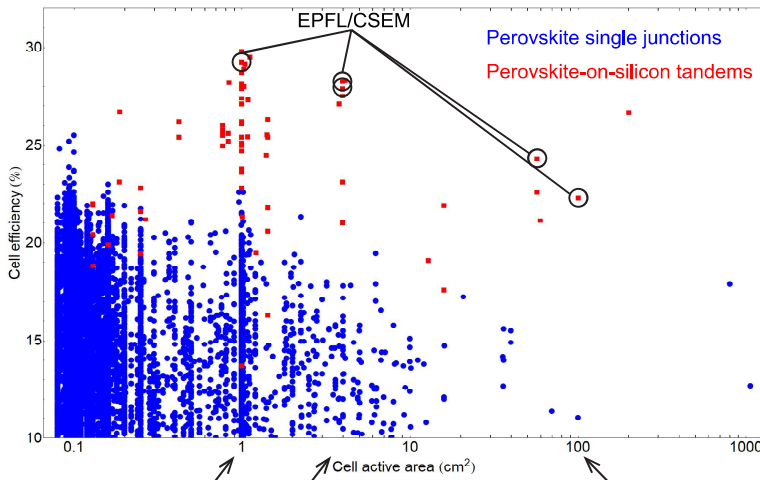
Increase the efficiency of perovskite-on-silicon tandem solar cells by developing materials, processes & device stacks

Scale-up the device dimensions from the 1 cm² of today to full-area >M6 wafers (silicon industry standard)

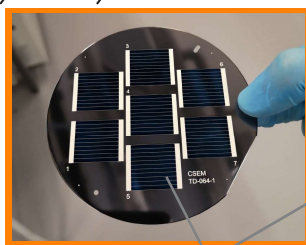
Develop **cell interconnection & encapsulation processes** leading to minimal cell-to-module losses

Extend the operational stability of perovskite solar cells, ideally to match the standards of silicon-based PV

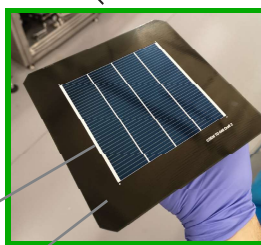
Literature review of the efficiency of perovskite single junctions & perovskite-on-silicon tandem solar cells as function of device dimension



Development of materials & processes on small dimensions



Industrial metallisation method - screen-printing of Ag paste at low temperature



Chemical etching of silicon wafer for compatibility with the deposition of the perovskite by meniscus coating

Tandem solar cells promise higher efficiencies

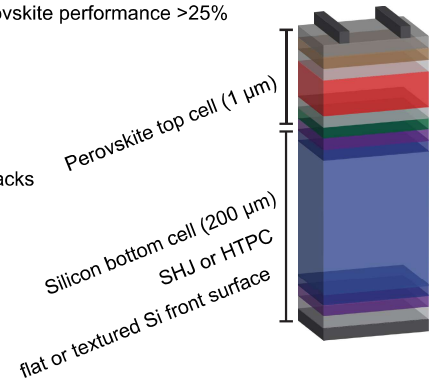
Reduction of losses by adding a second cell on a conventional silicon cell

Silicon, due to its intrinsic optical properties, is an ideal bottom cell

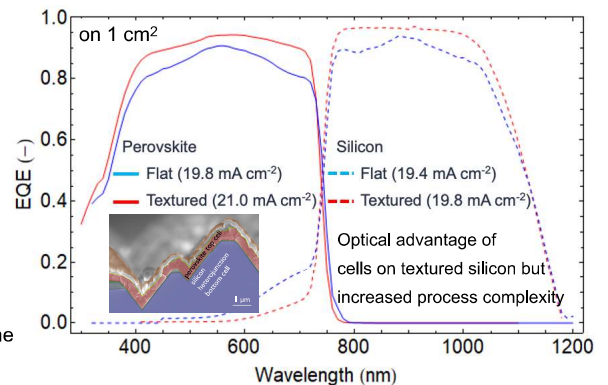
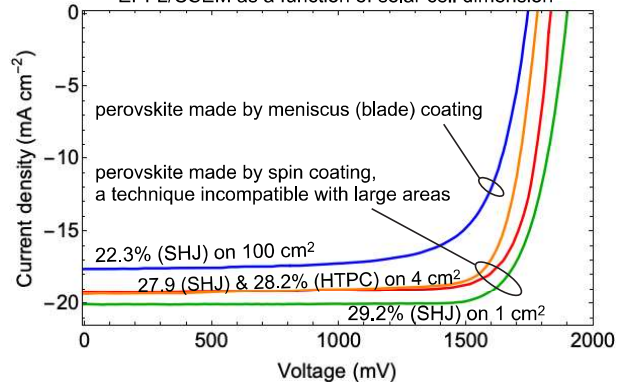
Record efficiency of 32.8% for a III-V-on-silicon tandem solar cell

Metal halide perovskite materials as cheaper alternatives to III-V materials

- Soft deposition conditions (<150°C), tunable bandgap, sharp absorption edge
- High single-junction perovskite performance >25%



Current-voltage properties of tandem cells made at EPFL/CSEM as a function of solar cell dimension



Summary of our results on perovskite-on-silicon tandem solar cells

Demonstration of **state-of-the-art perovskite-on-silicon tandem efficiencies from 1 cm² (29.2%), 4 cm² (28.2%) to 100 cm² (22.3%)**

Perovskite materials & deposition processes compatible with silicon cells that are either **textured (the industry standard)** or **chemically polished (to simplify the perovskite deposition process)** on their front side

High-efficiencies demonstrated on different types of bottom cells made in-house, **silicon heterojunction & cells based on high temperature passivating contacts (PERC upgrades)**

Demonstration of **processing techniques compatible with mass-manufacturing constraints** (meniscus coating to deposit the perovskite absorber, screen-printing for the front-side metallisation of the tandem)

Tandem solar cells made at EPFL/CSEM pass some of the IEC stability tests (damp heat, thermal cycling), the light soaking stability at elevated temperature needs to be improved (tests & improvements in progress)

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